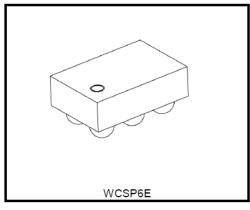


TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

TCK401G, TCK402G

External FET Driver IC

The TCK401G and TCK402G are 28 V high input voltage External FET driver ICs. They have wide input voltage range. And they feature a slew rate control driver with small package WCSP6E (0.8 mm x 1.2 mm, t: 0.55 mm). Also they can block reverse current if switch turned off by using external series FET. Thus they are suitable for power management selector such as Battery Charge application.

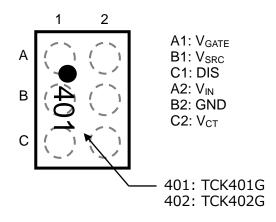


Weight: 1 mg(typ.)

Feature

- High maximum input voltage: V_{IN max} = 40 V
 Wide input voltage range: V_{IN} = 2.7 to 28 V
- Auto output discharge
- Charge pump circuit
- Inrush current reducing circuit.
- Over voltage lock out (Over 28 V)
- Under voltage lock out (Under 2.7 V)
- Reverse current protection by External Back to Back MOSFET

Top marking (Top view)



Start of commercial production 2017-10



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Input voltage	VIN	-0.3 to 40	V
Control voltage	Vст	-0.3 to 6	V
Output GATE voltage	VGATE	-0.3 to V _{IN} _opr + V _{GS}	V
SRC voltage	VsRC	-0.3 to V _{GATE}	V
DIS voltage	VDIS	-0.3 to 40	V
Power dissipation	PD	800 (Note 1)	mW
Operating temperature range	T _{opr}	-40 to 85	°C
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Rating at mounting on a board: FR4 board. ($40 \text{ mm} \times 40 \text{ mm} \times 1.6 \text{ mm}$, Cu 4 layer)

Operating Conditions

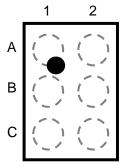
Characteristics	Symbol	Min.	Тур.	Max.	Unit
Input operation voltage	VIN _opr	2.7	5.0	28	V
Considered	CIN	0.1	1	_	μF
Capacitance	CGATE	_	2000	_	pF
CONTROL High-level input voltage	VIH	1.6		_	V
CONTROL Low-level input voltage	VIL	_	_	0.4	٧



• Pin Assignment (Top view)

WCSP6E

•

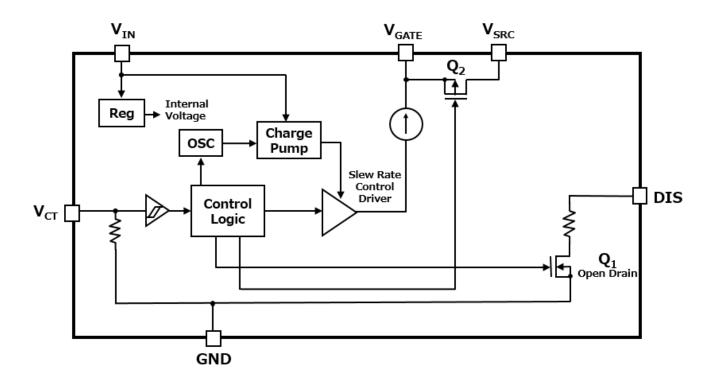


Pin #	Name	Pin#	Name
A 1	V _{GATE}	A2	V _{IN}
B1	V _{SRC}	B2	GND
C1	DIS	C2	V _{CT}

Product list

Part number	VCT function	VCT resistance
TCK401G	Active High	Pull down
TCK402G	Active Low	Pull down

Block Diagram





TCK401G PIN Description

PIN	Name	Description
A 1	V_{GATE}	Gate-Driver Output.
A2	Vin	Supply voltage input.
B1	V _{SRC}	Recommend connecting V _{SRC} terminal to the common source connection of the external MOSFETs.
B2	GND	Ground
C1	DIS	Output Discharge terminal.
C2	V _{CT}	Mode control input terminal. When V_{CT} =High turn the external MOSFETs on, V_{CT} =Low, turn the external MOSFETs off.

TCK402G PIN Description

PIN	Name	Description
A 1	V_{GATE}	Gate-Driver Output.
A2	V _{IN}	Supply voltage input.
B1	V _{SRC}	Recommend connecting V _{SRC} terminal to the common source connection of the external MOSFETs.
B2	GND	Ground
C1	DIS	Output Discharge terminal.
C2	V _{CT}	Mode control input terminal. When V_{CT} =Low turn the external MOSFETs on, V_{CT} =High, turn the external MOSFETs off.

•

TCK401G Operation Status Table

$2.7V \le V_{IN} \le 28 \text{ V (Ta} = -40 \text{ to } 85^{\circ}\text{C})$

V _{CT}	V_{GATE}	Discharge Q1	comment
High	ON (Vin + Vgs)	OFF	Driver ON mode
Open	OFF	ON	Driver OFF mode
Low	OFF	ON	Driver OFF mode

TCK402G Operation Status Table

$2.7V \le V_{IN} \le 28 \text{ V (Ta = -40 to } 85^{\circ}\text{C)}$

V _{CT}	V_{GATE}	Discharge Q1	comment		
Low	ON	OFF	Driver ON mode		
Open	ON (Vin + Vgs)	OFF			
High	OFF	ON	Driver OFF mode		



DC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C (Note 2)		Unit
				Min.	Тур.	Max.	Min	Max	
			V _{CT} : High, V _{IN} = 5.0 V	_	121	_	_	222	μА
		TOK 404 O	VCT: High, V _{IN} = 9.0 V	_	144	_	_	283	μΑ
		TCK401G	VcT: High, V _{IN} = 12 V	_	159	_	_	294	μА
			VcT: High, V _{IN} = 20 V	_	198	_	_	376	μА
Input quiescent current (ON state)	IQ(ON)		VCT: Low, VIN = 5.0 V	_	121	_	_	222	μА
		TOK 4000	VCT: Low, VIN = 9.0 V	_	144	_	_	283	μА
		TCK402G	V _{CT} : Low, V _{IN} = 12 V	_	159	_	_	294	μА
			V _{CT} : Low, V _{IN} = 20 V	_	198	_	_	376	μА
		TCK401G	V _{CT} : Low, V _{IN} = 5.0 V	_	3.0	_	_	4.8	μА
			V _{CT} : Low, V _{IN} = 9.0 V	_	5.9	_	_	8.2	μА
			VcT: Low, VIN = 12 V	_	8.0	_	_	11.2	μА
			VCT: Low, VIN = 20 V	_	13.8	_	_	19.2	μА
Standby current (OFF state)	IQ(OFF)		VcT: High, V _{IN} = 5.0 V	_	3.0	_	_	4.8	μА
			VcT: High, V _{IN} = 9.0 V	_	5.9	_	_	8.2	μА
		TCK402G	VcT: High, V _{IN} = 12 V	_	8.0	_	_	11.2	μА
			V _{CT} : High, V _{IN} = 20 V	_	13.8	_	_	19.2	μА
		V _{IN} = 3 V	,	_	4.0	_	2.8	5.1	٧
		V _{IN} = 5 V		_	6.5	_	5.1	7.9	V
GATE Drive voltage(VGATE-VIN)	VGS	VIN = 9.0 V	1	_	6.5	_	5.1	7.9	V
		12 V ≤ V _{IN} ≤ 28 V		_	8.5	_	6.9	10.0	٧
Output current	IGATE(ON)	VIN = 5 V		_	38	_	_	_	μА
DIS resistance	R _{DIS}				21		_	_	kΩ
Control pull down resistance	R _{CT}	V _{CT} = 5 V		_	600	_	_	_	kΩ

Note 2: This parameter is warranted by design.



AC Characteristics (Ta = 25°C, VIN = 5 V, CGATE = 2000 pF)

Characteristics	Symbol	Test Condition (Figure 1,2)	Min.	Тур.	Max.	Unit
VGATE ON time	ton	Initial startup time of VGATE (Note 3) voltage from 0 V to VIN +1 V	_	0.58	0.8	ms
VGATE OFF time	tOFF	V _{GATE} = 0.5 V	_	16.6	_	μS
V _{GATE} rise time	t _r	V _{GATE} rising from V _{IN} +1 V to V _{IN} +3 V	_	0.2		ms
VGATE fall time	tf	VGATE falling from V _{IN} +3 V to V _{IN} +1 V	_	1.5		μS

Note 3: This parameter is warranted by design.

AC Characteristics (Ta = 25°C, VIN = 9 V, CGATE = 2000 pF)

Characteristics	Symbol	Test Condition (Figure 1,2)	Min.	Тур.	Max.	Unit
VGATE ON time	ton	Initial startup time of V _{GATE} (Note 4) voltage from 0 V to V _{IN} +1 V		0.78	1.0	ms
VGATE OFF time	toff	VGATE = 0.5 V		19.7		μS
VGATE rise time	tr	VGATE rising from VIN +1 V to VIN +4 V		0.35	_	ms
V _{GATE} fall time	tf	V _{GATE} falling from V _{IN} +4 V to V _{IN} +1 V	_	1.6	_	μS

Note 4: This parameter is warranted by design.

AC Characteristics (Ta = 25°C, VIN = 12 V, CGATE = 2000 pF)

Characteristics	Symbol	Test Condition (Figure 1,2)	Min.	Тур.	Max.	Unit
VGATE ON time	ton	Initial startup time of VGATE (Note 5) voltage from 0 V to VIN +1 V	_	0.92	1.2	ms
V _{GATE} OFF time	toff	V _{GATE} = 0.5 V	_	21.3	_	μS
V _{GATE} rise time	t _r	V _{GATE} rising from V _{IN} +1 V to V _{IN} +5 V		0.6		ms
VGATE fall time	tf	VGATE falling from V _{IN} +5 V to V _{IN} +1 V	_	1.7	_	μS

Note 5: This parameter is warranted by design.



Timing chart

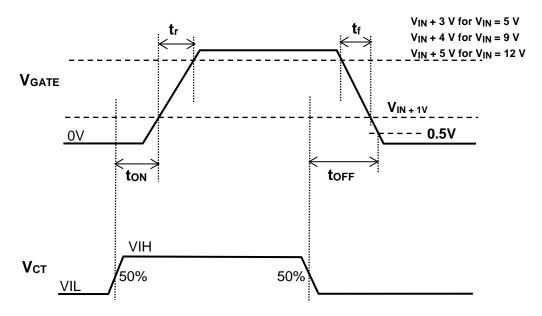


Fig.1 Active High (TCK401G)

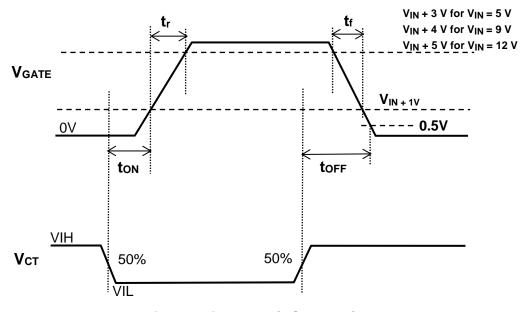
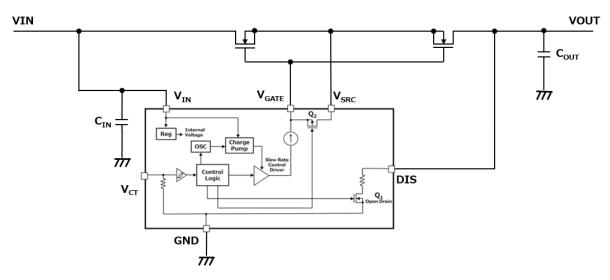


Fig.2 Active Low (TCK402G)



Application Note

Application circuit example



1) Input and Output capacitor

An input capacitor (C_{IN}) and an output capacitor (C_{OUT}) are recommended for the stable operation of TCK401G and TCK402G. And it is effective to reduce voltage overshoot or undershoot due to sharp changes in output current and also for improved stability of the power supply. When used, place C_{IN} and C_{OUT} more than $1.0\mu F$ as close to TCK40xG to improve stability of the power supply.

2) V_{CT} pin

 V_{CT} pin for TCK401G and TCK402G is operated by the control voltage and has Schmitt trigger. V_{CT} pin has a tolerant function such that it can be used even if the control voltage is higher than the input voltage.

3) VSRC Pin

For Dual MOSFET Driver, V_{SRC} works to short between V_{GATE} and MOSFET source when Driver IC turn off. If there are enough margins of V_{GS} of MOSFET, V_{SRC} terminal Open state is no problem.

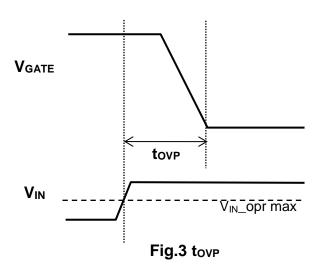
For Single MOSFET Driver, if there is enough margin of V_{GS} of MOSFET, V_{SRC} pin Open state is no problem. If there are not enough margins, we recommend connecting V_{SRC} and VOUT. If connect V_{SRC} and VOUT, t_{OFF} time become longer because of C_{OUT}. Therefore, please consider enough margins for MOSFET selection.

4) DIS Pin

If discharge function is needed when Driver IC turns off, please connect DIS Pin to V_{OUT} . If no need, DIS Pin Open state is no problem.

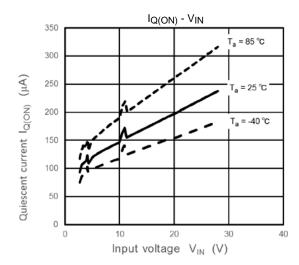
Over Voltage Protection off time (t_{OVP})
Over Voltage (V_{IN} is over V_{IN}_opr max) Protection off time (t_{OVP}) is similar to V_{GATE} OFF time (t_{OFF}).

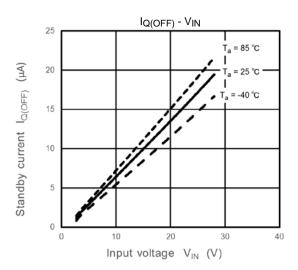
Timing chart

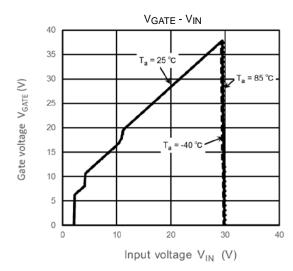


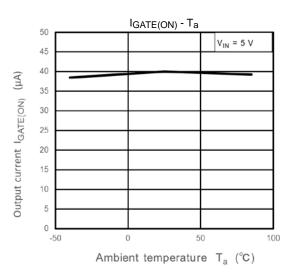


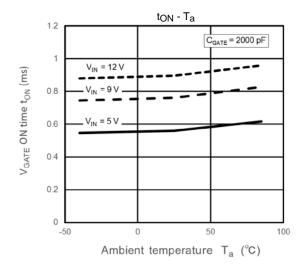
Representative Typical Characteristics

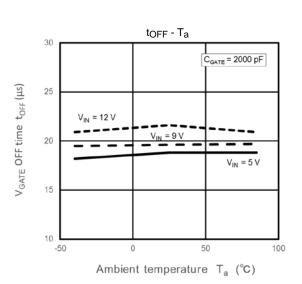




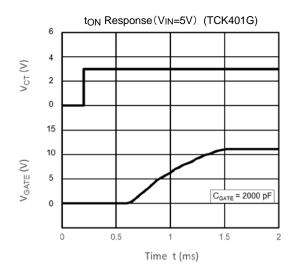


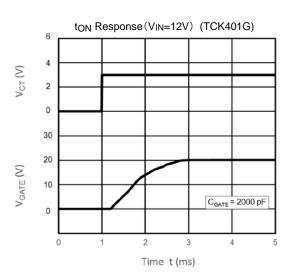


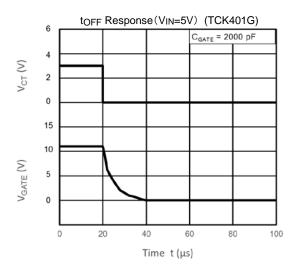


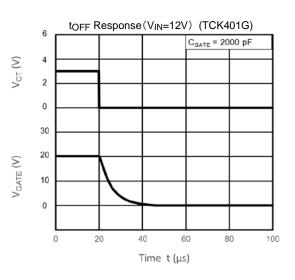










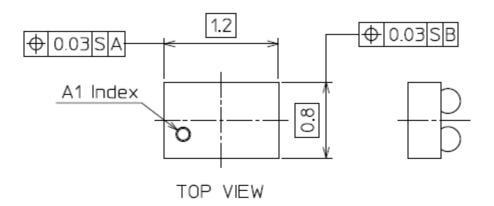


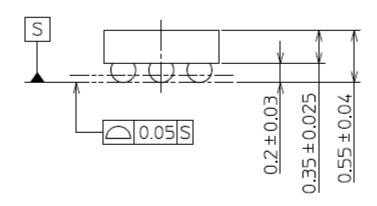
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

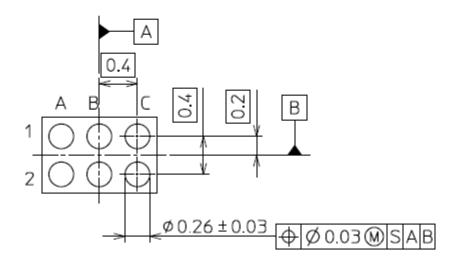


• Package dimension

Unit: mm







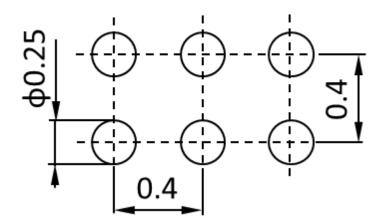
BOTTOM VIEW

Weight: 1 mg (typ.)



Land pattern dimensions (for reference only)

Unit: mm





RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY
 CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation,
 equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment,
 equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or
 explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE,
 TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our
 website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR
 PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER,
 INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING
 WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2)
 DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR
 INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE,
 ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for
 the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass
 destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations
 including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export
 and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and
 regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please
 use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including
 without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT
 OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Gate Drivers category:

Click to view products by Toshiba manufacturer:

Other Similar products are found below:

00053P0231 56956 57.404.7355.5 LT4936 57.904.0755.0 5882900001 00600P0005 00-9050-LRPP 00-9090-RDPP 5951900000 011003W-10/32-15 0131700000 00-2240 LTP70N06 LVP640 5J0-1000LG-SIL LY1D-2-5S-AC120 LY2-US-AC240 LY3-UA-DC24
00576P0020 00600P0010 LZN4-UA-DC12 LZNQ2M-US-DC5 LZNQ2-US-DC12 LZP40N10 00-8196-RDPP 00-8274-RDPP 00-8275RDNP 00-8722-RDPP 00-8728-WHPP 00-8869-RDPP 00-9051-RDPP 00-9091-LRPP 00-9291-RDPP 0207100000 0207400000 60100564
01312 0134220000 60713816 M15730061 61161-90 61278-0020 6131-204-23149P 6131-205-17149P 6131-209-15149P 6131-218-17149P
6131-220-21149P 6131-260-2358P 6131-265-11149P